OMRON

Photomicrosensor

EE-SX67/47

Photomicrosensor with 50- to 100-mA Switching Capacity that can be Built into Equipment

- PNP output models newly added.
- Standard, L-shaped, T-shaped, and Close-mounting: Five series of models available.
- Select from thirty output variations, including Light-ON or Dark-ON/Light-ON (selectable) models.
- Response frequency as high as 1 kHz.
- Easy operation monitoring with bright light indicator.
- Wide operating voltage range from 5 to 24 VDC.
- Models (EE-SX□□□A and EE-SX□□□R) with operation indicators that are lit when sensing objects are detected (when light is interrupted) are available.



Ordering Information

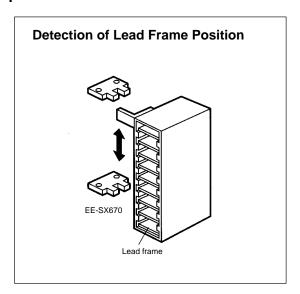
Appearance	Sensing method	Sensing	Output configuration	ı	Model	Weight
		distance		NPN	PNP	
Standard	Through-beam type (slot type)	5 mm (slot width)	Dark-ON/Light-ON (selectable) *1	EE-SX670 EE-SX670A*2	EE-SX670P EE-SX670R*3	Approx. 3.1 g
			Light-ON	EE-SX470	EE-SX470P	
L-shaped			Dark-ON/Light-ON (selectable) *1	EE-SX671 EE-SX671A*2	EE-SX671P EE-SX671R*3	Approx. 3.0 g
VIII T			Light-ON	EE-SX471	EE-SX471P	
T-shaped			Dark-ON/Light-ON (selectable) *1	EE-SX672 EE-SX672A*2	EE-SX672P EE-SX672R*3	Approx. 2.4 g
Glocal D			Light-ON	EE-SX472	EE-SX472P	
Close-mounting			Dark-ON/Light-ON (selectable) *1	EE-SX673 EE-SX673A*2	EE-SX673P EE-SX673R*3	Approx. 2.3 g
			Light-ON	EE-SX473	EE-SX473P	
Close-mounting			Dark-ON/Light-ON (selectable) *1	EE-SX674 EE-SX674A*2	EE-SX674P EE-SX674R*3	Approx. 3.0 g
2m			Light-ON	EE-SX474	EE-SX474P	

Note: *1. The Dark-ON/Light-ON (selectable) models can be used as Light-ON models when the L terminal and positive (+) terminal are short-circuited. An L terminal and positive (+) terminal short-circuit connector (EE-1001-1) is available.

^{*2.} Models with a suffix "A," such as EE-SX670A, have a Dark-ON indicator that is lit when light is interrupted.

^{*3.} Models with a suffix "R," such as EE-SX670R, have a Dark-ON indicator that is lit when light is interrupted.

Application Example



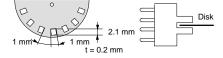
Specifications -

■ Ratings

Item	Output	Standard	L-shaped	T-shaped	Close-m	nounting	
	NPN	EE-SX670 EE-SX670A EE-SX470	EE-SX671 EE-SX671A EE-SX471	EE-SX672 EE-SX672A EE-SX472	EE-SX673 EE-SX673A EE-SX473	EE-SX674 EE-SX674A EE-SX474	
	PNP	EE-SX670P EE-SX670R EE-SX470P	EE-SX671P EE-SX671R EE-SX471P	EE-SX672P EE-SX672R EE-SX472P	EE-SX673P EE-SX673R EE-SX473P	EE-SX674P EE-SX674R EE-SX474P	
Sensing distance		5 mm (slot width)					
Standard sensing object		Opaque: 2 × 0.8 mm r	nin.				
Differential travel		0.025 mm					
Light source (peak wave length)		GaAs infrared LED (940 nm)					
Receiver		Si phototransistor with	a sensing wavelength	of 850 nm max.			
Operation indicator (see	note 1)	Operation indicator (re	ed) lit with incident (Mod	lels with a suffix of "A" of	or "R" have Dark-ON indic	cators.)	
Power supply voltage		5 to 24 VDC ±10%, rip	pple (p-p): 10% max.				
Current consumption		35 mA max. (NPN), 30	0 mA max. (PNP)				
Control output		NPN open collector output models: At 5 to 24 VDC: 100-mA load current (I _C) with a residual voltage of 0.8 V max. 40-mA load current (I _C) with a residual voltage of 0.4 V max. PNP open collector output models:					
At 5 to 24 VDC: 50-mA load current (I _C) with a residual voltage of 1.3 V max. Response frequency (see note 2) 1 kHz max. (3 kHz average)							

Note: 1. The indicator is GaP red LED (peak emission wavelength: 690 nm).

2. The response frequency was measured by detecting the following rotating disks.

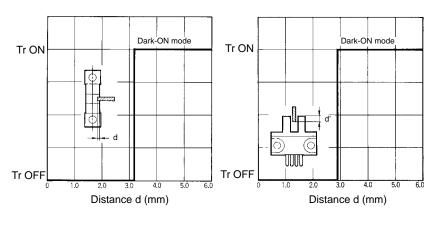


■ Characteristics

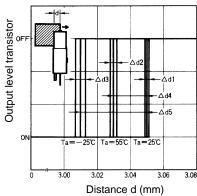
Item	Output	Standard	L-shaped	T-shaped	Close-	mounting
	NPN	EE-SX670 EE-SX670A EE-SX470	EE-SX671 EE-SX671A EE-SX471	EE-SX672 EE-SX672A EE-SX472	EE-SX673 EE-SX673A EE-SX473	EE-SX674 EE-SX674A EE-SX474
	PNP	EE-SX670P EE-SX670R EE-SX470P	EE-SX671P EE-SX671R EE-SX471P	EE-SX672P EE-SX672R EE-SX472P	EE-SX673P EE-SX673R EE-SX473P	EE-SX674P EE-SX674R EE-SX474P
Ambient illumination Fluorescent light: 1,000 ℓx max. (on Receiver lens)						
Ambient temperature Operating: -25° to 55°C Storage: -30° to 80°C						
Ambient humidity		Operating: 5% to 88 Storage: 5% to 98				
Vibration resistance		Destruction: 20 to 2,00 cycles) each in X, Y, a		eleration of 10G), 1.5-m	nm double amplitude for	2 hrs (with 4-minute
Shock resistance		Destruction: 500 m/s ²	(approx. 50G) for 3 tim	es each in X, Y, and Z	directions	
Degree of protection		IEC60529 IP50				
Connection method Connector type (direct soldering possible)						
Weight		Approx. 3.1 g	Approx. 3.0 g	Approx. 2.4 g	Approx. 2.3 g	Approx. 3.0 g
Material Case: Polybutylene phthalate (PBT)				Polycarbonate (PC), Em	nitter/receiver: Polycarbo	onate (PC)

Engineering Data

Sensing Position Characteristics (Typical)



Repeated Sensing Position Characteristics (Typical)



V_{cc} = 12 V No. of repetitions: 20

 $\Delta d1 = 0.002 \text{ mm}$ $\Delta d2 = 0.004 \text{ mm}$

 $\Delta d3 = 0.005 \text{ mm}$

 $\Delta d4 = 0.02 \text{ mm}$

 $\Delta d5 = 0.04 \text{ mm}$

Operation ———

■ Output Circuit Diagrams

Output configuration	Model	Output transistor operation	Timing Charts	Output Circuit
NPN Output	EE-SX670 EE-SX671 EE-SX672 EE-SX673 EE-SX674	Light-ON (When terminals L and ⊕ are short-cir Incident Interrupted Operation On indicator (red) OFF Output transistor OFF Load 1 (relay) Operates Releases Load 2 H L Dark-ON (When terminals L and ⊕ are open) Incident Interrupted Operation O		Operation Operat
			transistor OFF Load 1 (relay) Operates Releases Load 2 H L	
	EE-SX470 EE-SX471 EE-SX472 EE-SX473 EE-SX474	Light-ON	Incident Interrupted Operation ON indicator (red) OFF Output transistor OFF Load 1 (relay) Operates Releases Load 2 H L	Operation (red) Note: When using on voltage output, always insert a resistor in RL.
	EE-SX670A EE-SX671A EE-SX672A EE-SX673A EE-SX674A	Light-ON	(When terminals L and ⊕ are short-circuited) Incident Interrupted Operation ON OFF Output ON transistor OFF Load 1 (relay) Operates Releases Load 2 H L	Operation indicator (red) Main circuit Operation (red) Out I Coad 1 (relay) See note)
		Dark-ON	(When terminals L and ⊕ are open) Incident Interrupted Operation ON OFF Output transistor Load 1 (relay) Operates Releases Load 2 H L	Note: When using on voltage output, always insert a resistor in RL.

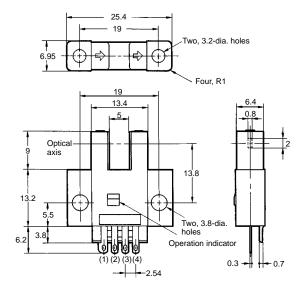
Output configuration	Model	Output transistor operation	Timing Charts	Output Circuit
PNP Output	EE-SX670P EE-SX671P EE-SX672P EE-SX673P EE-SX674P	Light-ON	(When terminals L and ⊕ are short-circuited) Incident Interrupted Operation ON OFF Output ON transistor OFF Load (relay) Operates Releases Voltage output H L	Operation indicator (red) Main circuit Load RL
		Dark-ON	(When terminals L and ⊕ are open) Incident Interrupted Operation ON OFF Output transistor OFF Load 1 (relay) Operates Releases Load 2 H L	Note: When using on voltage output, always insert a resistor in RL.
	EE-SX470P EE-SX471P EE-SX472P EE-SX473P EE-SX474P	Light-ON	Operation indicator (red) OFF Output transistor OFF Load (relay) Operates Releases Voltage output H L	Operation indicator (red) Main circuit Note: When using on voltage output, always insert a resistor in RL.
	EE-SX670R EE-SX671R EE-SX672R EE-SX673R EE-SX674R	Light-ON Dark-ON	(When terminals L and ⊕ are short-circuited) Incident Interrupted □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □ □	Operation indicator (red) Main circuit Note: When using on voltage output, always insert a resistor in RL.

Dimensions

Note: All units are in millimeters unless otherwise indicated.

EE-SX670/670P EE-SX670A/670R EE-SX470/470P





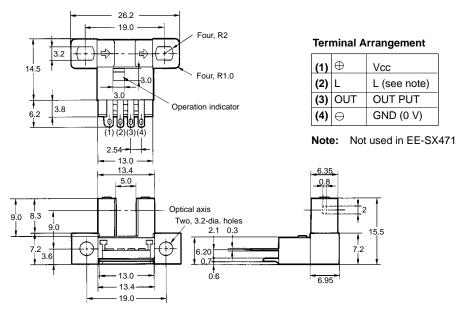
Terminal Arrangement

(1)	\oplus	Vcc		
(2)	L	L (see note)		
(3)	OUT	OUT PUT		
(4)	\ominus	GND (0 V)		

Note: Not used in EE-SX470

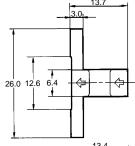






EE-SX672/672P EE-SX672A/672R EE-SX472/472P

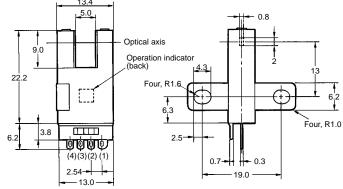




Terminal Arrangement

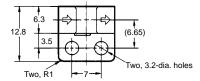
(1)	\oplus	Vcc
(2)	L	L (see note)
(3)	OUT	OUT PUT
(4)	Θ	GND (0 V)

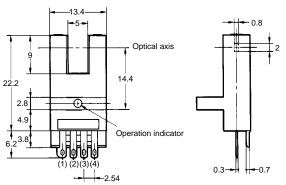
Note: Not used in EE-SX472



EE-SX673/673P EE-SX673A/673R EE-SX473/473P







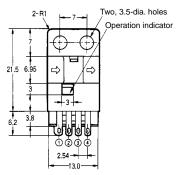
Terminal Arrangement

(1)	\oplus	Vcc
(2)	L	L (see note)
(3)	OUT	OUT PUT
(4)	Θ	GND (0 V)

Note: Not used in EE-SX473



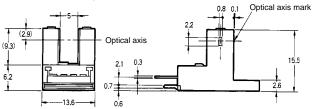




Terminal Arrangement

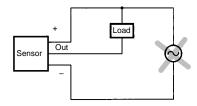
(1)	\oplus	Vcc
(2)	L	L (see note)
(3)	OUT	OUT PUT
(4)	Θ	GND (0 V)

Note: Not used in EE-SX474

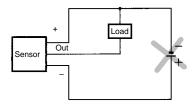


Precautions

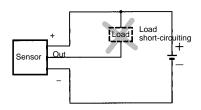
Do not use the EE-SX at voltage exceeding the rated voltage range, otherwise the EE-SX may be damaged.



Do not make mistakes in wiring, such as mistakes in polarity, otherwise the EE-SX may be damaged.



Do not short-circuit the load (i.e., do not connect a power supply directly to the Sensor) as shown below, otherwise the EE-SX may be damaged.





Mounting

The EE-SX is a Sensor to be built into equipment. Therefore, no special protective measures have been taken to protect the EE-SX from external light disturbance. Make sure that the EE-SX is not affected by incandescent lamps or other light sources that may cause external light disturbance, otherwise the EE-SX may malfunction.

Be sure to mount the Sensor securely to flat plates. The characteristics of the Through-beam Sensor change if the slot is deformed.

Use M3.0 screws when mounting the EE-SX. Be sure to use spring washers with the screws so that the screws will not loosen. The tightening torque applied to each screw must be no more than $0.59~N \cdot m$ (6 kgf \cdot cm).

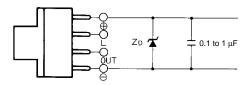
Make sure that nothing will come into contact with the sensing element of the Sensor. If the sensing element has scratch damage, the characteristics of the Sensor will decrease.

Make sure that the EE-SX is securely mounted and not loosened by vibration or shock.

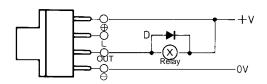
Wiring

Countermeasures Against Surge

If the power supply has surge voltage, connect a Zener diode with standing 30 to 35 V or 0.1 to 1- μ F capacitor in parallel to the power supply to absorb the surge voltage.



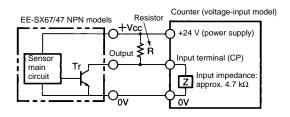
If the load is a relay or other small inductive load, connect the load to the EE-SX as shown below. Be sure to connect a diode for countervoltage absorption.



Do not wire power lines or high-tension lines alongside the lines of the EE-SX in the same conduit, otherwise the EE-SX may be damaged or malfunction due to induction. Be sure to wire the lines of the EE-SX separately from power lines or high-tension lines or lay them in an exclusive, shielded conduit.

Voltage Output

A Sensor with open collector output can be connected to a device with voltage-input specifications by connecting a resistor between the power supply and output terminals as shown in the following circuit diagram. The resistance of the resistor is normally 4.7 $\mbox{k}\Omega$ and must withstand a power of 0.5 W at 24 V and 0.25 W at 12 V.



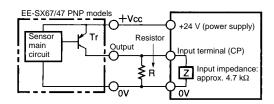
EE-SX47/67 NPN Models with a 4.7-k Ω Resistor High level:

Input voltage (V_H) =
$$\frac{Z}{R+Z}$$
 V_{CC} = $\frac{4.7 \text{ k}}{4.7 \text{ k} + 4.7 \text{ k}}$ x 24 V = 12 V

Low level:

Input voltage $(V_I) \leq 0.4 \text{ V}$

Load current (I_C) =
$$\frac{V_{CC}}{R}$$
 = $\frac{24 \text{ V}}{R}$ = 5.1 mA \leq 50 to 100 mA



EE-SX47/67 PNP Models with a 4.7-k Ω Resistor High level:

Input voltage (V_H) = Vcc–residual voltage
$$\approx$$
 24 V–1.3 V=22.7 V

Low level:

Input voltage (V_L) ≈0 V

Note: Refer to the ratings of the Sensor for the relationship between the residual voltage and load current.

Others

Do not wire the EE-SX while power is applied, otherwise the EE-SX may be damaged.

Do not install the EE-SX in the following locations, otherwise the EE-SX may be damaged or malfunction.

Locations with excessive dust

Locations with corrosive gas

Locations where water, oil, or chemical is directly sprayed

Outdoors or locations exposed to direct sunlight

Make sure that the operating ambient temperature is within the rated range.

The Sensor may be soluble in organic solvent, acid, and alkaline, aromatic hydrocarbon, and chlorinated aliphatic hydrocarbon solvents. The characteristics of the Sensor may decrease as a result. Therefore, make sure that the Sensor is free from these solutions.

■ Additional Models (EE-SX77/87)

Ordering Information —

Appearance	Sensing method	Sensing distance	Output		Model
			configuration	NPN	PNP
Standard		1	Dark ON	EE-SX770	EE-SX770P
				EE-SX770A	EE-SX770R
		1 1 1	Light ON	EE-SX870	EE-SX870P
Į II		1 1		EE-SX870A	EE-SX870R
L-shaped	Through-beam (slot)	1 1	Dark ON	EE-SX771	EE-SX771P
		5 mm		EE-SX771A	EE-SX771R
		(slot width)	Light ON	EE-SX871	EE-SX871P
N				EE-SX871A	EE-SX871R
T-shaped]	1	Dark ON	EE-SX772	EE-SX772P
		1		EE-SX772A	EE-SX772R
		 	Light ON	EE-SX872	EE-SX872P
		1		EE-SX872A	EE-SX872R

Specifications —

■ Ratings/Characteristics

Item	Through-beam models(slot)								
Output configuration	Dark ON				Light ON				
Output	NI	PN	PN	IP	NI	PN	PI	PNP	
Model	EE-SX770 EE-SX771 EE-SX772	EE-SX770A EE-SX771A EE-SX772A	EE-SX770P EE-SX771P EE-SX772P	EE-SX770R EE-SX771R EE-SX772R	EE-SX870 EE-SX871 EE-SX872	EE-SX870A EE-SX871A EE-SX872A	EE-SX870P EE-SX871P EE-SX872P	EE-SX870R EE-SX871R EE-SX872R	
Sensing distance	5 mm (slot widt	th)							
Standard sensing object	Opaque: 2 x 0.	8 mm min							
Operation indicator (see note)	Operation indic	ator (red) lit with	ncident (Models v	vith a suffix of "A"	or "R" have Dai	k-ON indicators.)		
Power supply voltage	5 to 24 VDC \pm	5 to 24 VDC ± 10%, ripple (p-p): 10% max.							
Current consumption	35 mA max. (N	PN), 30 mA max.	(PNP)						
Control output	. At 5		els: ·mA load current (I _C) with a residua			/ max.			
		ector output mode 5 to 24 VDC: 50-n	ls: nA load current (I ₀	c) with a residual	voltage of 1.3 V	max.			
Ambient illuminance	Sensing surfac	e: 1,000 ℓx max.	with fluorescent li	ght					
Ambient temperature									
Ambient humidity	Operating: 5% to 85% Storage: 5% to 95%								
Degree of protection	IEC60529 IP60								
Connection method (standard length)	Pre-wired: 2 m	Pre-wired: 2 m							
Weight	Approx. 20 g								

Note: The indicator is GaP red LED (peak emission wavelength: 690 nm).

Operation ———

■ Output Circuits

Output configuration	Model	Output transistor operation	Т	iming Charts	Output Circuit
NPN Output	EE-SX770 EE-SX771 EE-SX772 EE-SX770A EE-SX771A EE-SX772A	Dark-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF Operate Reset	Operation Load (e.g., relay) Black 5 to 24 VDC
	EE-SX870 EE-SX871 EE-SX872 EE-SX870A EE-SX871A EE-SX872A	Light-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF OPERATE Reset	(Red) Main Control output 100 mA max.
PNP Output	EE-SX770P EE-SX771P EE-SX772P EE-SX770R EE-SX771R EE-SX772R	Dark-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF Operate Reset	Operation indicator Control output Black 50 mA max.
	EE-SX870P EE-SX871P EE-SX872P EE-SX870R EE-SX871R EE-SX872R	Light-ON	Operation indicator (red) Output transistor Load (e.g., relay)	Incident Interrupted ON OFF ON OFF OPERATE Reset	(Red) Circuit 5 to 24 VDC Load Load Blue (e.g., relay)

■ Notice

Photomicrosensors (EE-SX67/47, 77/87 models) and Connectors (EE-1001/1001-1/1006/1009/1010/1010-R) have been certified as products that conform to the following UL Standard.

Certified Date: February 9, 1998

Certified Models: All OMRON EE-SX67/47-series Photomicrosensors and the Photomicrosensor Connectors

(EE-1001/1001-1/1006/1009/1010/1010-R)

File No.: E41515

Standard Name: UL508: industrial control devices

Certification Method: UL Recognition (recognition for products used in the U.S.A.) and Canadian UL Recognition (recog-

nition certification for products used in Canada)

Applicable Lot No.: 928 and after (products manufactured on and after February 9, 1998)

The following Photomicrosensors have been certified as products conforming to the EMC Directives (CE marking).

CE Marking Date: April 1, 1998

Applicable Models: All EE-SX67/47 (A) models, EE-SX67/47 P, R models

All EE-SX77/87 (A) models, EE-SX77/87 P, R models

EE-SY671/672 EE-SPW311/411 EE-SPY311/312 EE-SPY301/302 EE-SPY401/402 EE-SPY411/412

EE-SPX302/304/306-W2A EE-SPX402/404/406-W2A

EE-SPX303/403 EE-SPX301/401

ALL DIMENSIONS SHOWN ARE IN MILLIMETERS.

To convert millimeters into inches, multiply by 0.03937. To convert grams into ounces, multiply by 0.03527.

Cat. No. E303-E1-1 In the interest of product improvement, specifications are subject to change without notice.

OMRON Corporation

Industrial Sensors Division Sensing Devices and Components Division H.Q. 28th Fl., Crystal Tower Bldg., 1-2-27, Shiromi, Chuo-ku, Osaka 540-6028 Japan

Phone: (81)6-949-6012 Fax: (81)6-949-6021

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